## NSN 5962-01-256-2986

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View Online at https://aerobasegroup.com/nsn/5962-01-256-2986 **Body Length:** 1.290 inches **Body Width:** 0.610 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 1.02 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and programmable and schottky and w/active pull-up and 3-state output **Inclosure Material:** Ceramic and glass **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 14 input **Case Outline Source And Designator:** D-3 mil-m-38510 **Terminal Surface Treatment:** Gold or solder **Voltage Rating And Type Per Characteristic:** -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 100.00 nanoseconds propagation delay time, low to high level output and 100.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Rom **Memory Capacity:** 

Unknown

**Precious Material And Location:** 

Terminal surface option gold

**Precious Material:** 

Gold

**Test Data Document:** 

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

**Terminal Type And Quantity:** 

24 printed circuit

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Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

Yes - demil/mli

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